NSN 5961-01-356-4291

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-356-4291 **Inclosure Material:** Glass **Overall Length:** Between 0.125 inches and 0.250 inches **Terminal Length:** Between 0.700 inches and 1.300 inches **Overall Diameter:** Between 0.065 inches and 0.085 inches **Mounting Method: Terminal Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 160.0 breakdown voltage, dc and 150.0 working peak reverse voltage **Current Rating Per Characteristic:** 2.50 amperes forward current, average absolute and 35.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Nuclear hardness critical item; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No